

isc N-Channel MOSFET Transistor

STP75NF75

FEATURES

- Drain Current –I_D= 80A@ T_C=25 °C
- Drain Source Voltage-
 - : V_{DSS}= 75V(Min)
- · Static Drain-Source On-Resistance
 - : $R_{DS(on)} = 0.011 \Omega (Max)$
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRIPTION

Suitable as primary switch in advanced high-efficiency, high-frequency isolated DC-DC converters for Telecom and Computer applications. It is also intended for any application with low gate drive requirements .

APPLICATIONS

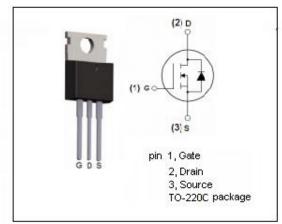
Switching application

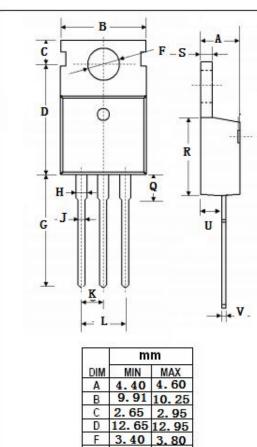
ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	75	٧
V _{GS}	Gate-Source Voltage-Continuous	±20	٧
I _D	Drain Current-Continuous	80	Α
I _{DM}	Drain Current-Single Pluse	320	Α
P_D	Total Dissipation @T _C =25℃	300	W
TJ	Max. Operating Junction Temperature	175	$^{\circ}$
T _{stg}	Storage Temperature	-55~175	$^{\circ}$

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	0.5	°C/W
R _{th j-a}	Thermal Resistance, Junction to Ambient	62.5	°C/W





DIM	MIN	MAX	
Α	4.40	4.60	
В	9.91	10.25	
C	2.65	2.95	
D	12.65	12.95	
F	3.40	3.80	
G	12.9	13.4	
Н	1.17	1.37	
J	0.71	0.91	
K	2. 54		
L	4.98	5. 18	
Q	2.85	3. 25	
R	8.95	9.75	
S	1.20	1.40	
U	2. 25	2. 55	
V	0.33	0.65	



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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D = 0.25mA	75		V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D = 0.25mA	2	4	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 40A		0.011	Ω
I _{GSS}	Gate-Body Leakage Current	V _{GS} = ±20V;V _{DS} = 0		±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} = 75V; V _{GS} = 0 V _{DS} = 75V; V _{GS} = 0; T _j = 125°C		1 10	μ А
V _{SD}	Forward On-Voltage	I _S = 80A; V _{GS} =0		1.5	V

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